

SESD Series Ultra Low Capacitance Discrete TVS AUTOMOTIVE GRADE ROHS PO







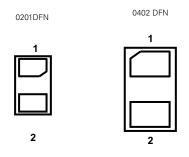




Description

The SESD Series Ultra Low Capacitance Discrete TVS provides unidirectional and bidirectional ESD protection for the world's most challenging high speed serial interfaces. Ultra low capacitance permits excellent signal integrity on the most challenging consumer electronics interfaces, such as USB 3.1, HDMI 2.0, DisplayPort, and V-by-One®. Providing in excess of 20kV contact ESD protection (IEC61000-4-2) while maintaining extremely low leakage and dynamic resistance, offered in the industry's most popular footprints (0402 and 0201), the SESD series sets higher standards for signal integrity and usability.

Pinout



Bottom View

Features

- 0.13pF MAX bidirectional
- 0.25pF MAX unidirectional
- ESD, IEC61000-4-2, ±20kV contact, ±20kV air
- Low clamping voltage of 10V @ $I_{pp} = 2A$ (Bidirectional) (t_p=8/20µs)
- Low profile 0201 and 0402 DFN packages
- Facilitates excellent signal integrity
- AEC-Q101 qualified
- ELV Compliant

Functional Block Diagram





Unidirectional

Bidirectional

Applications

- Ultra-high speed data lines
- USB 3.1, 3.0, 2.0
- HDMI 2.0, 1.4a, 1.3
- DisplayPort^(TM)
- Thunderbolt (Light Peak)
- V-by-One®
- LVDS interfaces

- Consumer, mobile and portable electronics
- Tablet PC and external storage with high speed interfaces
- Applications requiring high ESD performance in small packages

TVS Diode Arrays (SPA®Diodes)

SESD Series Enhanced ESD Diode Arrays

Absolute Maximum Ratings					
Symbol	Parameter	Value	Units		
I _{PP}	Peak Current (t _p =8/20µs)	2.0	А		
T _{OP}	Operating Temperature	-55 to 125	°C		
Т	Storage Temperature	-55 to 150	°C		

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Thermal Information					
Parameter	Rating	Units			
Storage Temperature Range	-55 to 150	°C			
Maximum Junction Temperature	150	°C			
Maximum Lead Temperature (Soldering 20-40s)	260	°C			

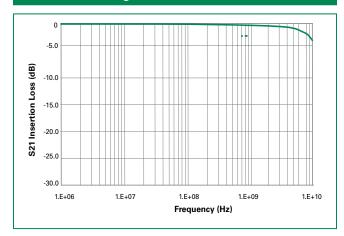
Unidirectional Electrical Characteristics - (T_{OP}=25°C)

Parameter	Test Conditions	Min	Тур	Max	Units	
Input Capacitance	@ V _R = 0V, f = 3GHz		0.20	0.25	pF	
Breakdown Voltage	V _{BR} @ I _T =1mA		9.00		V	
Reverse Working Voltage				7.0	V	
Reverse Leakage Current	I _L @ V _{RWM} =5.0V		25	50	nA	
Clamping Voltage	V _{CL} @ I _{PP} =2.0A		9.20		V	
ESD Withstand Voltage	IEC61000-4-2 (Contact)	±20			kV	
E3D Willistand Voltage	IEC61000-4-2 (Air)	±20			- KV	

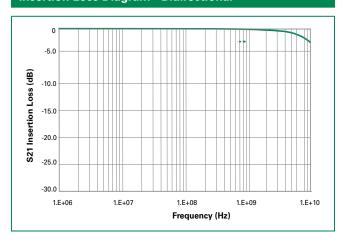
Bidirectional Electrical Characteristics - (T_{OP}=25°C)

Parameter	Test Conditions	Min	Тур	Max	Units	
Input Capacitance	@ V _R = 0V, f = 3GHz		0.10	0.13	pF	
Breakdown Voltage	V _{BR} @ I _T =1mA		9.80		V	
Reverse Working Voltage		-7.0		7.0	V	
Reverse Leakage Current	I _L @ V _{RWM} =5.0V		25	50	nA	
Clamping Voltage	V _{CL} @ I _{PP} =2.0A		10.0		V	
ESD Withstand Voltage	IEC61000-4-2 (Contact)	±20			kV	
LOD WithStalia Voltage	IEC61000-4-2 (Air)	±20			- KV	

Insertion Loss Diagram - Unidirectional

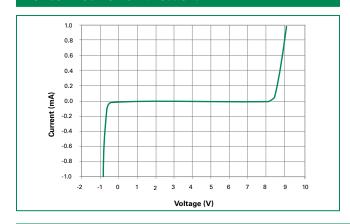


Insertion Loss Diagram - Bidirectional

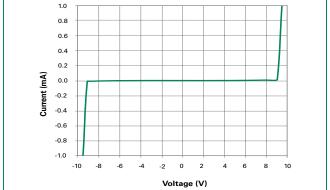




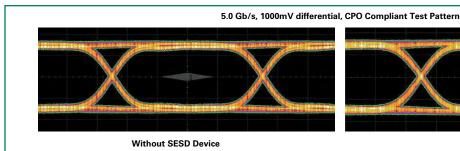
Device IV Curve - Unidirectional

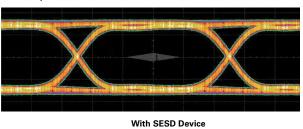


Device IV Curve - Bidirectional 1.0 0.8 0.6



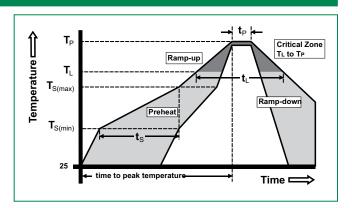
USB3.0 Eye Diagram





Soldering Parameters

Reflow Cor	ndition	Pb – Free assembly
	-Temperature Min (T _{s(min)})	150°C
Pre Heat	-Temperature Max (T _{s(max)})	200°C
	-Time (min to max) (t _s)	60 – 180 secs
Average ra to peak	mp up rate (Liquidus) Temp (T _L)	3°C/second max
$T_{S(max)}$ to T_{L}	- Ramp-up Rate	3°C/second max
Reflow	-Temperature (T _L) (Liquidus)	217°C
nellow	-Temperature (t _L)	60 – 150 seconds
Peak Temp	erature (T _P)	260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t _p)		20 – 40 seconds
Ramp-dow	n Rate	6°C/second max
Time 25°C	to peak Temperature (T _P)	8 minutes Max.
Do not exc	eed	260°C



Product Characteristics of 0402 DFN Package

Lead Plating	Pre-Plated Frame
Lead Material	Copper Alloy
Lead Coplanarity	0.0004 inches (0.102mm)
Substrate material	Silicon
Body Material	Molded Epoxy
Flammability	UL 94 V-0

- All dimensions are in millimeters
 Dimensions include solder plating.
- 3. Dimensions are exclusive of mold flash & metal burr.

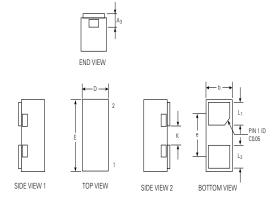
 4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.

 5. Package surface matte finish VDI 11-13.

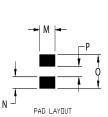
TVS Diode Arrays (SPA®Diodes)

SESD Series Enhanced ESD Diode Arrays

Package Dimensions — 0201 DFN

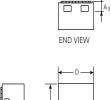


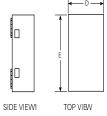
Symbol	Millimeters			Inches		
Зуптрог	Min	Тур	Max	Min	Тур	Max
А	0.28	0.30	0.32	0.011	0.012	0.013
A1	0	-	0.05	0	-	0.002
А3		0.102 ref.			0.004 ref.	
D	0.25	0.30	0.35	0.010	0.012	0.014
Е	0.55	0.60	0.65	0.022	0.024	0.026
K	0.11	0.17	0.22	0.004	0.007	0.009
b	0.20	0.25	0.30	0.008	0.010	0.012
L1	0.13	0.18	0.23	0.005	0.008	0.009
L2	0.14	0.19	0.24	0.006	0.007	0.009
е		0.356 BS0	2		0.014 BSC	;
М		0.32			0.013	
N		0.24			0.009	
0		0.62			0.024	
Р		0.14			0.006	

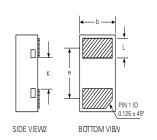


END VIEW

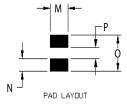
Package Dimensions — 0402 DFN





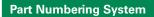


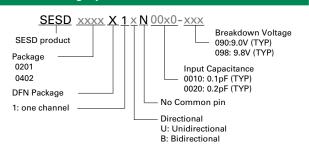




Cumphial	Millimeters			Inches		
Symbol	Min	Тур	Max	Min	Тур	Max
А	0.33	0.38	0.43	0.013	0.015	0.017
A1	0	-	0.05	0	-	0.002
А3		0.13 ref.			0.005 ref.	•
D	0.55	0.60	0.65	0.022	0.024	0.026
Е	0.95	1.00	1.05	0.037	0.039	0.041
K	0.35	0.40	0.45	0.014	0.016	0.018
b	0.45	0.50	0.55	0.018	0.020	0.022
L	0.20	0.25	0.30	0.008	0.010	0.012
е		0.65 BSC	;		0.026 BS0	
М		0.60			0.024	
N		0.35			0.014	
0		1.00			0.039	
Р		0.30			0.012	







Part Marking System





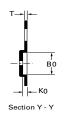


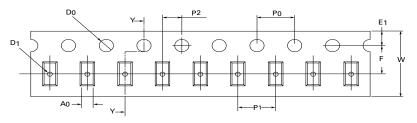
Bidirectional

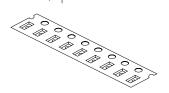
Ordering Information

Part Number	Package	Marking	Ordering Part Number	Components/Reel Quantity
SESD0201X1UN-0020-090	0201 DFN	I C	RF2192-000	15000
SESD0201X1BN-0010-098	0201 DFN	С	RF2193-000	15000
SESD0402X1UN-0020-090	0402 DFN	I C	RF2943-000	10000
SESD0402X1BN-0010-098	0402 DFN	С	RF2945-000	10000

Embossed Carrier Tape & Reel Specification — 0201 DFN

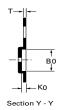


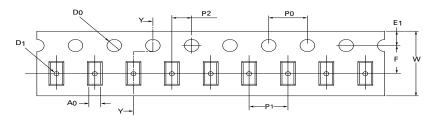


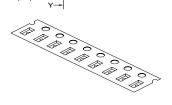


Symbol	Millimeters
A0	0.36+/-0.03
В0	0.66+/-0.03
D0	ø 1.50 + 0.10/-0
D1	ø 0.20 +/- 0.05
E1	1.75+/-0.10
F	3.50+/-0.05
K0	0.33+/-0.03
P0	4.00+/-0.10
P1	2.00+/-0.10
P2	2.00+/-0.05
W	8.00 +/-0.10
Т	0.23+/-0.02

Embossed Carrier Tape & Reel Specification — 0402 DFN







Symbol	Millimeters
A0	0.70+/-0.05
В0	1.15+/-0.05
D0	ø 1.55 + 0.05
D1	ø 0.40 +/- 0.05
E1	1.75+/-0.10
F	3.50+/-0.05
K0	0.47+/-0.05
P0	4.00+/-0.10
P1	2.00+/-0.10
P2	2.00+/-0.05
W	8.00 +/-0.10
Т	0.20+/-0.05